

MOS FIELD EFFECT TRANSISTOR 2SK3385

SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

DESCRIPTION

The 2SK3385 is N-Channel MOS Field Effect Transistor designed for high current switching applications.

FEATURES

- Low On-state Resistance
- ★ RDS(on)1 = 28 m Ω MAX. (VGS = 10 V, ID = 15 A) RDS(on)2 = 45 m Ω MAX. (VGS = 4.0 V, ID = 15 A)
 - Low Ciss : Ciss = 1500 pF TYP.
 - Built-in Gate Protection Diode
 - TO-251/TO-252 package

ORDERING INFORMATION

PART NUMBER	PACKAGE		
2SK3385	TO-251		
2SK3385-Z	TO-252		

ABSOLUTE MAXIMUM RATINGS (TA = 25 °C)

	Drain to Source Voltage	Voss	60	V
	Gate to Source Voltage	Vgss	±20	V
	Drain Current (DC)	ID(DC)	±30	Α
*	Drain Current (Pulse) Note1	I D(pulse)	±100	Α
*	Total Power Dissipation (Tc = 25°C)	Рт	36	W
	Total Power Dissipation (T _A = 25°C)	Рт	1.0	W
	Channel Temperature	Tch	150	°C
	Storage Temperature	Tstg	-55 to +150	°C
*	Single Avalanche Current Note2	las	22	Α
*	Single Avalanche Energy Note2	Eas	48	mJ

Notes 1. PW \leq 10 μ s, Duty cycle \leq 1 %

2. Starting Tch = 25 °C, RG = 25 Ω , VGS = 20 V \rightarrow 0 V

THERMAL RESISTANCE

*	Channel to Case	Rth(ch-C)	3.47	°C/W	
	Channel to Ambient	Rth(ch-A)	125	°C/W	

(TO-251)



(TO-252



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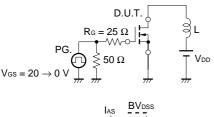
Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

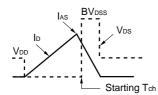


★ ELECTRICAL CHARACTERISTICS (TA = 25 °C)

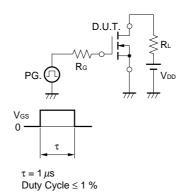
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CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain to Source On-state Resistance	RDS(on)1	Vgs = 10 V, ID = 15 A		22	28	mΩ
	R _{DS(on)2}	Vgs = 4.0 V, ID = 15 A		31	45	mΩ
Gate to Source Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	1.5	2.0	2.5	V
Forward Transfer Admittance	yfs	V _{DS} = 10 V, I _D = 15 A	8	16		S
Drain Leakage Current	Ipss	Vps = 60 V, Vgs = 0 V			10	μΑ
Gate to Source Leakage Current	lgss	Vgs = ±20 V, Vps = 0 V			±10	μΑ
Input Capacitance	Ciss	Vps = 10 V		1500		pF
Output Capacitance	Coss	Vgs = 0 V		250		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		130		pF
Turn-on Delay Time	td(on)	I _D = 15 A		22		ns
Rise Time	tr	V _{GS(on)} = 10 V		250		ns
Turn-off Delay Time	td(off)	V _{DD} = 30 V		77		ns
Fall Time	tf	$R_G = 10 \Omega$		77		ns
Total Gate Charge	Q _G	ID = 30 A		30		nC
Gate to Source Charge	Qgs	V _{DD} = 48 V		4.8		nC
Gate to Drain Charge	Q _{GD}	V _{GS(on)} = 10 V		8.6		nC
Body Diode Forward Voltage	VF(S-D)	IF = 30 A, VGS = 0 V		1.0		V
Reverse Recovery Time	trr	IF = 30 A, VGS = 0 V		44		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		79		nC

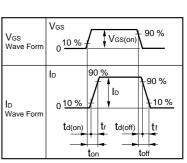
TEST CIRCUIT 1 AVALANCHE CAPABILITY



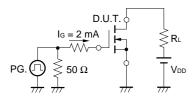


TEST CIRCUIT 2 SWITCHING TIME





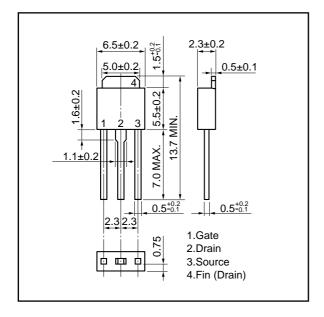
TEST CIRCUIT 3 GATE CHARGE



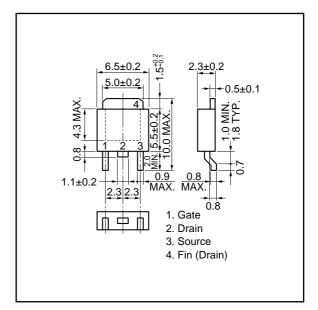


PACKAGE DRAWINGS (Unit: mm)

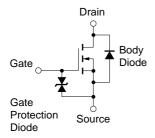
1) TO-251 (MP-3)



2) TO-252 (MP-3Z)



EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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